

# Current Transducers HTB 50..400-P/SP5 and HTB 50..100-TP/SP5

For the electronic measurement of currents: DC, AC, pulsed, mixed, with a galvanic isolation between the primary circuit (high power) and the secondary circuit (electronic circuit).





Electrical data							
Primary not current rm $I_{PN}$ (A)		Туре					
50 100 200 300 400	± 150 ± 300 ± 500 ± 600 ± 600	HTB 50-P/SP5, HTB 50-TP/S HTB 100-P/SP5, HTB 100-TI HTB 200-P/SP5 HTB 300-P/SP5 HTB 400-P/SP5					
<b>V</b> <sub>c</sub>	Supply voltage (± 5 %) <sup>2</sup>	)	+ 12 15	V			
I <sub>c</sub>	Current consumption		< 15	mΑ			
$\mathbf{V}_{d}$	Rms voltage for AC isol	ation test, 50 Hz, 1 min	2.5	kV			
R <sub>IS</sub>	Isolation resistance @ :	500 VDC	> 500	$M\Omega$			
V <sub>OUT</sub>	Output voltage (Analog)	@ $\pm$ <b>I</b> <sub>PN</sub> , <b>R</b> <sub>L</sub> = 10 kΩ, <b>T</b> <sub>A</sub> = 25°C	V <sub>OE</sub> ± 1.66	7 V			
$\mathbf{R}_{\scriptscriptstyle{OUT}}$	Output internal resistan	ice	100	$\Omega$			
$R_{\scriptscriptstyle L}$	Load resistance		≥ 10	$k\Omega$			

Accuracy - Dynamic performance data					
X	Accuracy @ $I_{PN}$ , $T_A = 25^{\circ}C$ (excluding offset)	< ± 1	% of <b>I</b> <sub>PN</sub>		
$\mathbf{e}_{\scriptscriptstyle oldsymbol{oldsymbol{L}}}$	Linearity error $(0 \pm I_{PN})$	< ± 1	% of I <sub>PN</sub>		
$\mathbf{V}_{_{\mathrm{OE}}}$	Electrical offset voltage @ T <sub>A</sub> = 25°C	$Vc/2 \pm 3$	0 mV		
<b>V</b> <sub>OH</sub>	Hysteresis offset voltage $@$ $I_p = 0$ ,				
	after an excursion of 1 x I <sub>PN</sub>	$< \pm 0.5$	% of I <sub>PN</sub>		
TCV <sub>OE</sub>	Temperature coefficient of V <sub>OE</sub> HTB 50-(T)P/SP5	$< \pm 1.0$	mV/K		
	HTB100-(T)P400-P/SP5	$< \pm 0.5$	mV/K		
TCV <sub>OUT</sub>	Temperature coefficient of $\mathbf{V}_{OUT}$ (% of reading)	$< \pm 0.05$	%/K		
t <sub>r</sub>	Response time to 90% of $I_{PN}$ step	< 3	μs		
BW	Frequency bandwidth (03 dB) <sup>3)</sup>	DC 50	) kHz		

General data						
$T_{_{A}}$	Ambient operating temperature	- 25 + 85	°C			
T <sub>s</sub>	Ambient storage temperature	- 25 + 85	°C			
m	Mass (-TP version)	< 30 (< 36)	g			

# $I_{PN} = 50 ... 400 A$





#### **Features**

- Hall effect measuring principle
- Galvanic isolation between primary and secondary circuit
- Isolation voltage 2500V
- Low power consumption
- Primary bus bar option for 50A and 100A version for ease of connection

### Special feature

• Single power supply from 12V to 15V

#### **Advantages**

- · Small size and space saving
- Only one design for wide current ratings range
- High immunity to external interference.

#### **Applications**

- AC variable speed drives
- Static converters for DC motor drives
- Battery supplied applications
- Uninterruptible Power Supplies (UPS)
- Switched Mode Power Supplies (SMPS)
- Power supplies for welding applications.

#### Notes :

- 1) -TP version is equipped with a primary bus bar.
- 2) Operating at +12V \le Vc < +15V will reduce measuring range.
- <sup>3)</sup> Derating is needed to avoid excessive core heating at high frequency.



## **Dimensions HTB 50..400-P/SP5 and HTB 50..100-TP/SP5** (in mm. 1 mm = 0.0394 inch)

## HTB 50..400-P/SP5 Left view **Back view** Positive Current Flow 14 MAX. ⊗ 34 3-0.635x0.635 Secondary Pin Identification 2-d2 1 +Vc Mounting Pins 2 0V 3 Output **Bottom View** HTB 50..100-TP/SP5 Left view **Back view** 14 MAX. 8 34 3-0.635x0.635 Positive Current Flow 2-P=2.5 10.5 <sub>3</sub> Secondary Pin Identification 6-1.5x1.5 1 +Vc 2 0V 3 Output

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**Bottom view**